

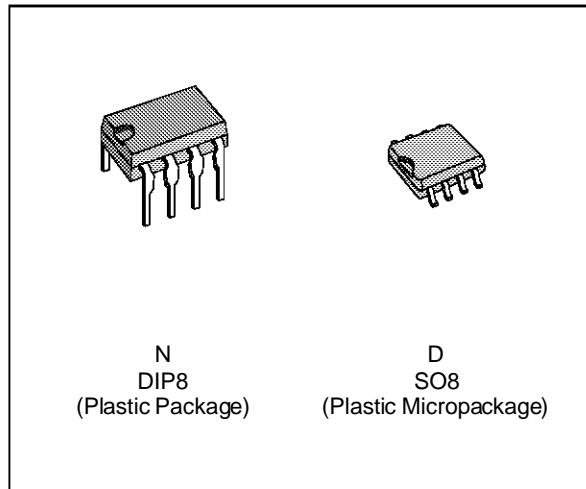


**SGS-THOMSON**  
MICROELECTRONICS

**TL071**  
**TL071A - TL071B**

**LOW NOISE  
SINGLE J-FET OPERATIONAL AMPLIFIERS**

- LOW POWER CONSUMPTION
- WIDE COMMON-MODE (UP TO  $V_{CC}^+$ ) AND DIFFERENTIAL VOLTAGE RANGE
- LOW INPUT BIAS AND OFFSET CURRENT
- LOW NOISE  $e_n = 15\text{nV}/\sqrt{\text{Hz}}$  (typ)
- OUTPUT SHORT-CIRCUIT PROTECTION
- HIGH INPUT IMPEDANCE J-FET INPUT STAGE
- LOW HARMONIC DISTORTION : 0.01% (typ)
- INTERNAL FREQUENCY COMPENSATION
- LATCH UP FREE OPERATION
- HIGH SLEW RATE : 16V/ $\mu\text{s}$  (typ)



#### DESCRIPTION

The TL071, TL071A and TL071B are high speed J-FET inputs single operational amplifiers incorporating well matched, high voltage J-FET and bipolar transistors in a monolithic integrated circuit.

The devices feature high slew rates, low input bias and offset currents, and low offset voltage temperature coefficient.

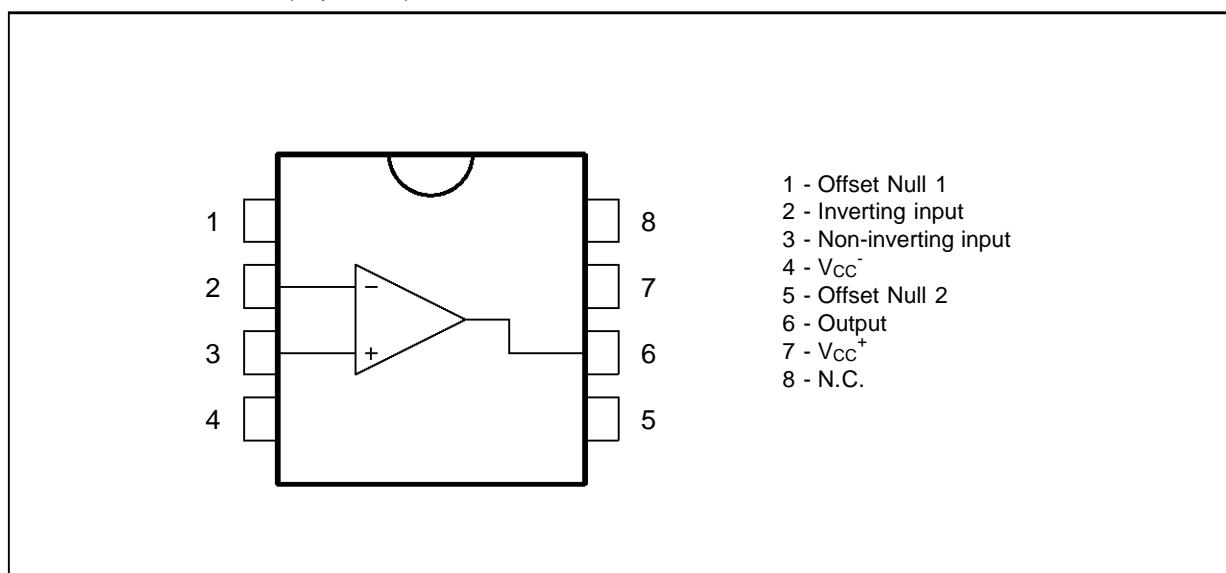
#### ORDER CODES

Part Number	Temperature Range	Package	
		N	D
TL071M/AM/BM	-55°C, +125°C	•	•
TL071I/AI/BI	-40°C, +105°C	•	•
TL071C/AC/BC	0°C, +70°C	•	•

Example : TL071CN

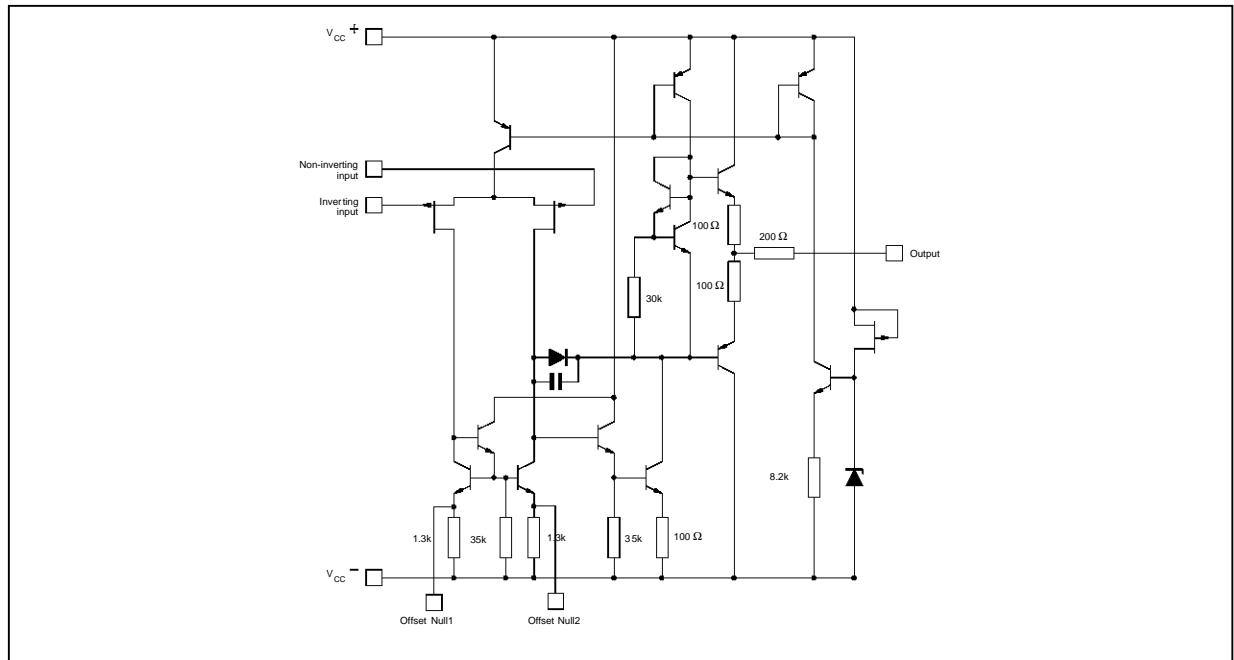
071-01-TBL

#### PIN CONNECTIONS (top view)

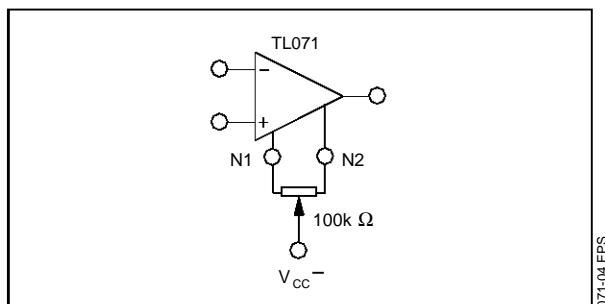


## TL071 - TL071A - TL071B

### SCHEMATIC DIAGRAM



### INPUT OFFSET VOLTAGE NULL CIRCUITS



### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply Voltage - (note 1)	$\pm 18$	V
$V_i$	Input Voltage - (note 3)	$\pm 15$	V
$V_{id}$	Differential Input Voltage - (note 2)	$\pm 30$	V
$P_{tot}$	Power Dissipation	680	mW
	Output Short-circuit Duration - (note 4)	Infinite	
$T_{oper}$	Operating Free Air Temperature Range TL071C,AC,BC TL071I,AI,BI TL071M,AM,BM	0 to 70 -40 to 105 -55 to 125	°C
$T_{stg}$	Storage Temperature Range	-65 to 150	°C

Notes :

- All voltage values, except differential voltage, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between  $V_{CC}^+$  and  $V_{CC}^-$ .
- Differential voltages are at the non-inverting input terminal with respect to the inverting input terminal.
- The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.
- The output may be shorted to ground or to either supply. Temperature and /or supply voltages must be limited to ensure that the dissipation rating is not exceeded.

071-02.TBL

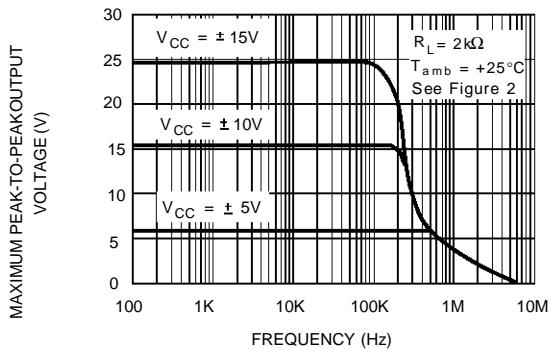
**ELECTRICAL CHARACTERISTICS** $V_{CC} = \pm 15V, T_{amb} = 25^{\circ}C$  (unless otherwise specified)

Symbol	Parameter	TL071I,M,AC,AI, AM,BC,BI,BM			TL071C			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	
$V_{io}$	Input Offset Voltage ( $R_S = 50\Omega$ ) $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$ TL071BC,BI,BM TL071BC,BI,BM		3 1	6 3 7 5		3	10 13	mV
$DV_{io}$	Input Offset Voltage Drift		10			10		$\mu V/^{\circ}C$
$I_{io}$	Input Offset Current * $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		5	100 4		5	100 10	pA nA
$I_{ib}$	Input Bias Current * $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		20	200 20		20	200 20	pA nA
$A_{vd}$	Large Signal Voltage Gain ( $R_L = 2k\Omega$ , $V_O = \pm 10V$ ) $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	50 25	200		25 15	200		V/mV
SVR	Supply Voltage Rejection Ratio ( $R_S = 50\Omega$ ) $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	80 80	86		70 70	86		dB
$I_{cc}$	Supply Current, no Load $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		1.4	2.5 2.5		1.4	2.5 2.5	mA
$V_{icm}$	Input Common Mode Voltage Range	$\pm 11$	+15 -12		$\pm 11$	+15 -12		V
CMR	Common Mode Rejection Ratio ( $R_S = 50\Omega$ ) $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	80 80	86		70 70	86		dB
$I_{os}$	Output Short-circuit Current $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	10 10	40	60 60	10 10	40	60 60	mA
$\pm V_{OPP}$	Output Voltage Swing $T_{amb} = 25^{\circ}C$ $R_L = 2k\Omega$ $R_L = 10k\Omega$ $T_{min.} \leq T_{amb} \leq T_{max.}$ $R_L = 2k\Omega$ $R_L = 10k\Omega$	10 12 10 12	12 13.5		10 12 10 12	12 13.5		V
SR	Slew Rate ( $V_{in} = 10V$ , $R_L = 2k\Omega$ , $C_L = 100pF$ , $T_{amb} = 25^{\circ}C$ , unity gain)	8	16		8	16		$V/\mu s$
$t_r$	Rise Time ( $V_{in} = 20mV$ , $R_L = 2k\Omega$ , $C_L = 100pF$ , $T_{amb} = 25^{\circ}C$ , unity gain)		0.1			0.1		$\mu s$
Kov	Overshoot ( $V_{in} = 20mV$ , $R_L = 2k\Omega$ , $C_L = 100pF$ , $T_{amb} = 25^{\circ}C$ , unity gain)		10			10		%
GBP	Gain Bandwidth Product ( $f = 100kHz$ , $T_{amb} = 25^{\circ}C$ , $V_{in} = 10mV$ , $R_L = 2k\Omega$ , $C_L = 100pF$ )	2.5	4		2.5	4		MHz
$R_i$	Input Resistance		$10^{12}$			$10^{12}$		$\Omega$
THD	Total Harmonic Distortion ( $f = 1kHz$ , $A_V = 20dB$ , $R_L = 2k\Omega$ , $C_L = 100pF$ , $T_{amb} = 25^{\circ}C$ , $V_O = 2V_{PP}$ )		0.01			0.01		%
$e_n$	Equivalent Input Noise Voltage ( $f = 1kHz$ , $R_S = 100\Omega$ )		15			15		$\frac{nV}{\sqrt{Hz}}$
$\emptyset m$	Phase Margin		45			45		Degrees

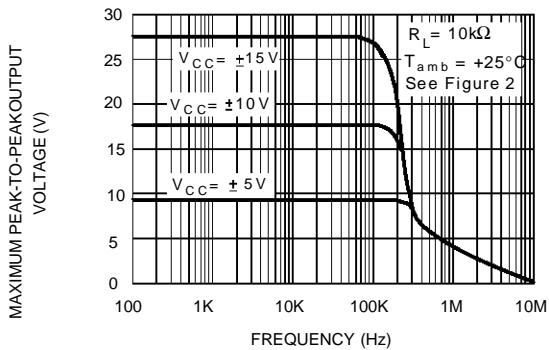
\* The input bias currents are junction leakage currents which approximately double for every  $10^{\circ}C$  increase in the junction temperature.

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**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE VERSUS FREQUENCY**

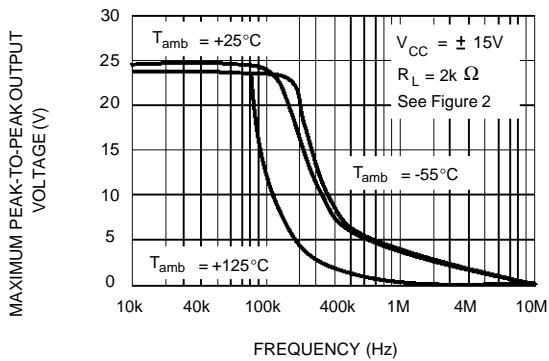


**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE VERSUS FREQUENCY**

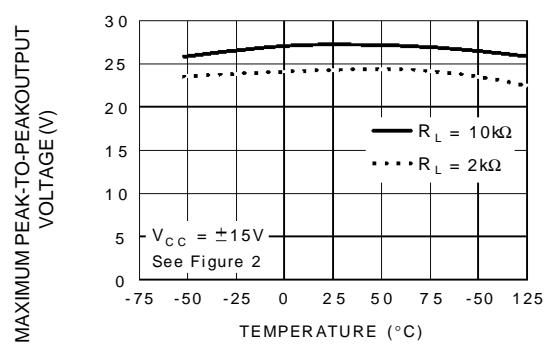


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**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE VERSUS FREQUENCY**

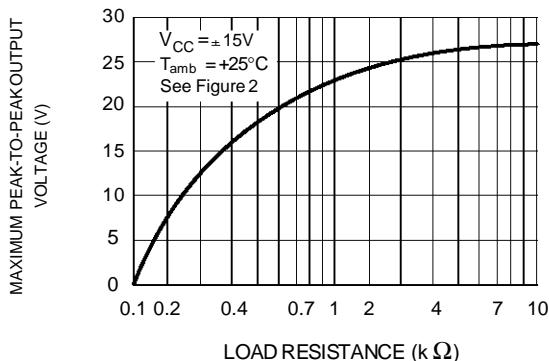


**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE VERSUS FREE AIR TEMP.**

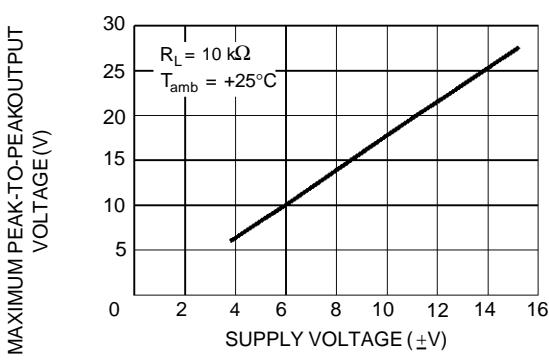


071-08.EPS

**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE VERSUS LOAD RESISTANCE**

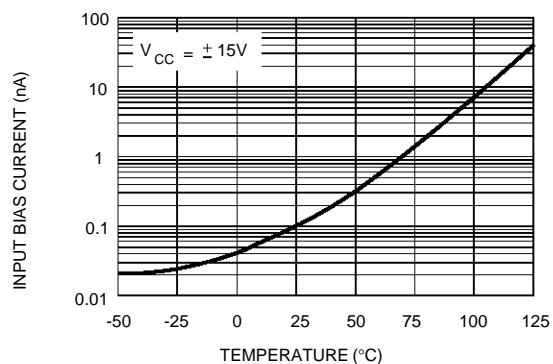


**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE VERSUS SUPPLY VOLTAGE**



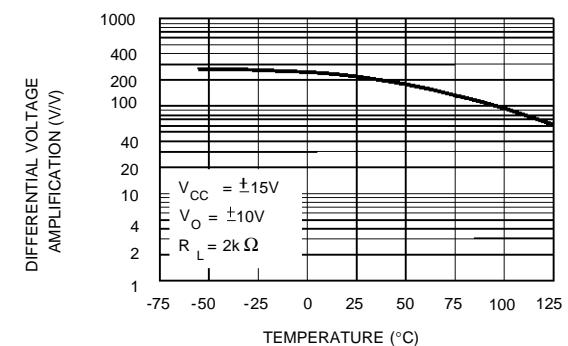
071-10.EPS

**INPUT BIAS CURRENT VERSUS  
FREE AIR TEMPERATURE**



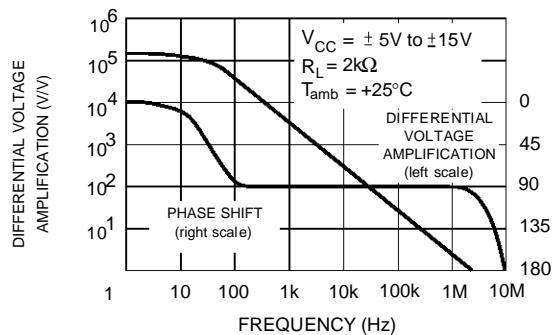
071-11.EPS

**LARGE SIGNAL DIFFERENTIAL  
VOLTAGE AMPLIFICATION VERSUS  
FREE AIR TEMPERATURE**



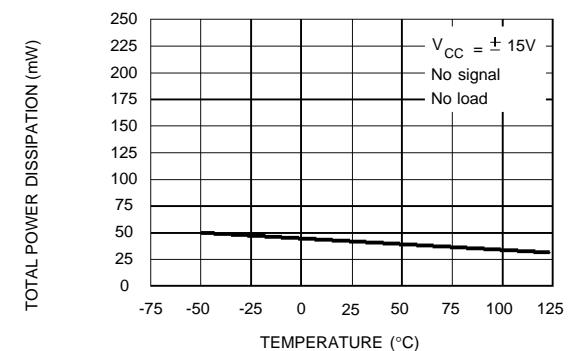
071-12.EPS

**LARGE SIGNAL DIFFERENTIAL  
VOLTAGE AMPLIFICATION AND PHASE  
SHIFT VERSUS FREQUENCY**



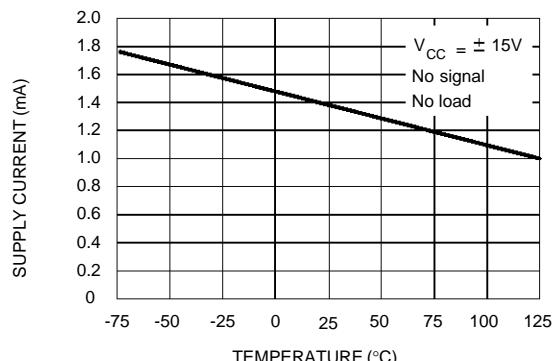
071-13.EPS

**TOTAL POWER DISSIPATION VERSUS  
FREE AIR TEMPERATURE**



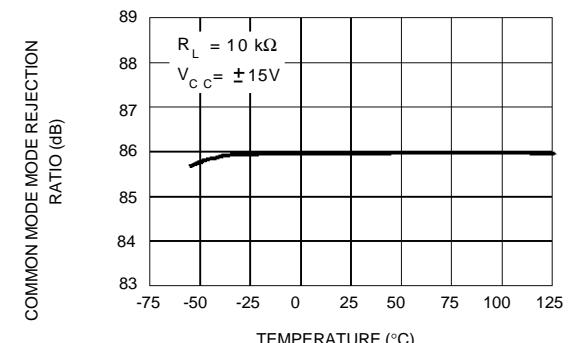
071-14.EPS

**SUPPLY CURRENT PER AMPLIFIER  
VERSUS FREE AIR TEMPERATURE**



071-15.EPS

**COMMON MODE REJECTION RATIO  
VERSUS FREE AIR TEMPERATURE**

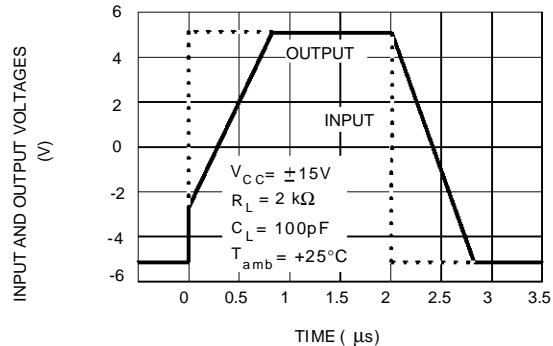


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## TL071 - TL071A - TL071B

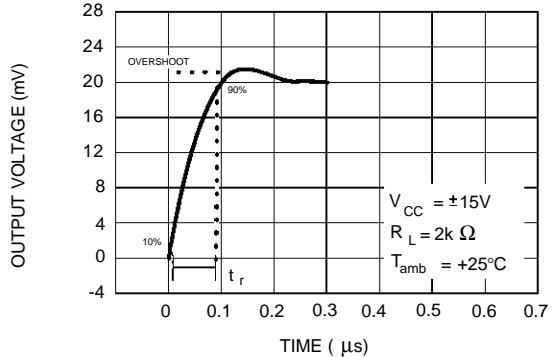
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### VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE



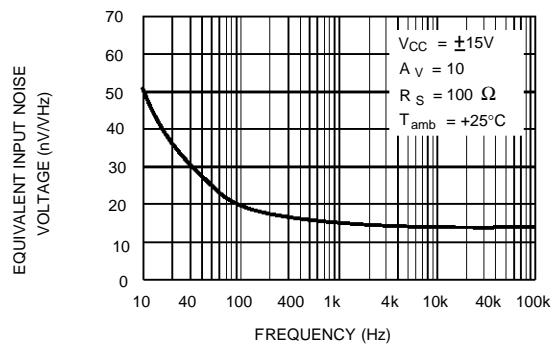
071-17.EPS

### OUTPUT VOLTAGE VERSUS ELAPSED TIME



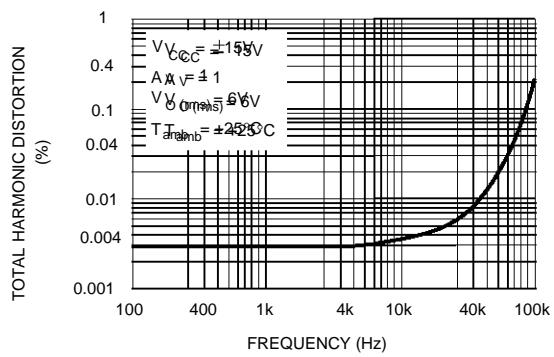
071-18.EPS

### EQUIVALENT INPUT NOISE VOLTAGE VERSUS FREQUENCY



071-19.EPS

### TOTAL HARMONIC DISTORTION VERSUS FREQUENCY



071-20.EPS

**PARAMETER MEASUREMENT INFORMATION**

Figure 1 : Voltage Follower

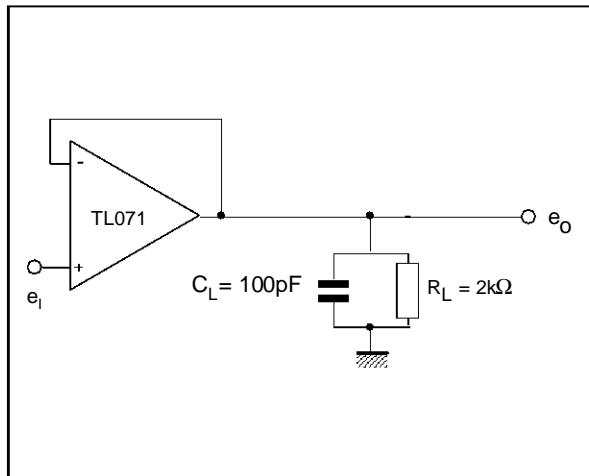
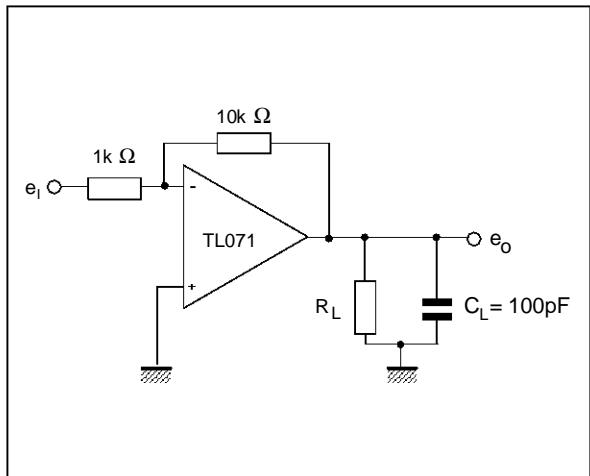
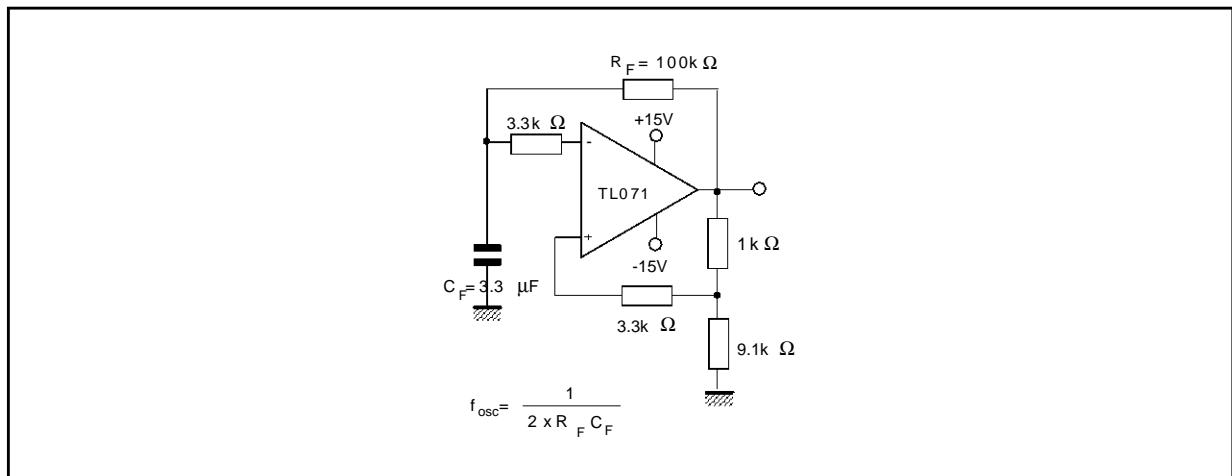


Figure 2 : Gain-of-10 Inverting Amplifier

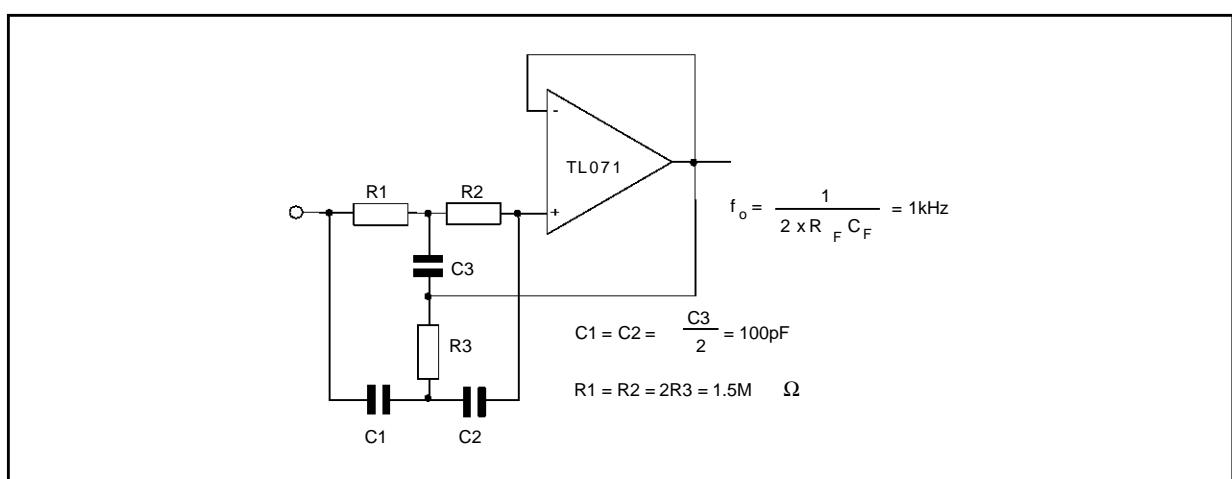


**TYPICAL APPLICATIONS**

(0.5Hz) SQUARE WAVE OSCILLATOR



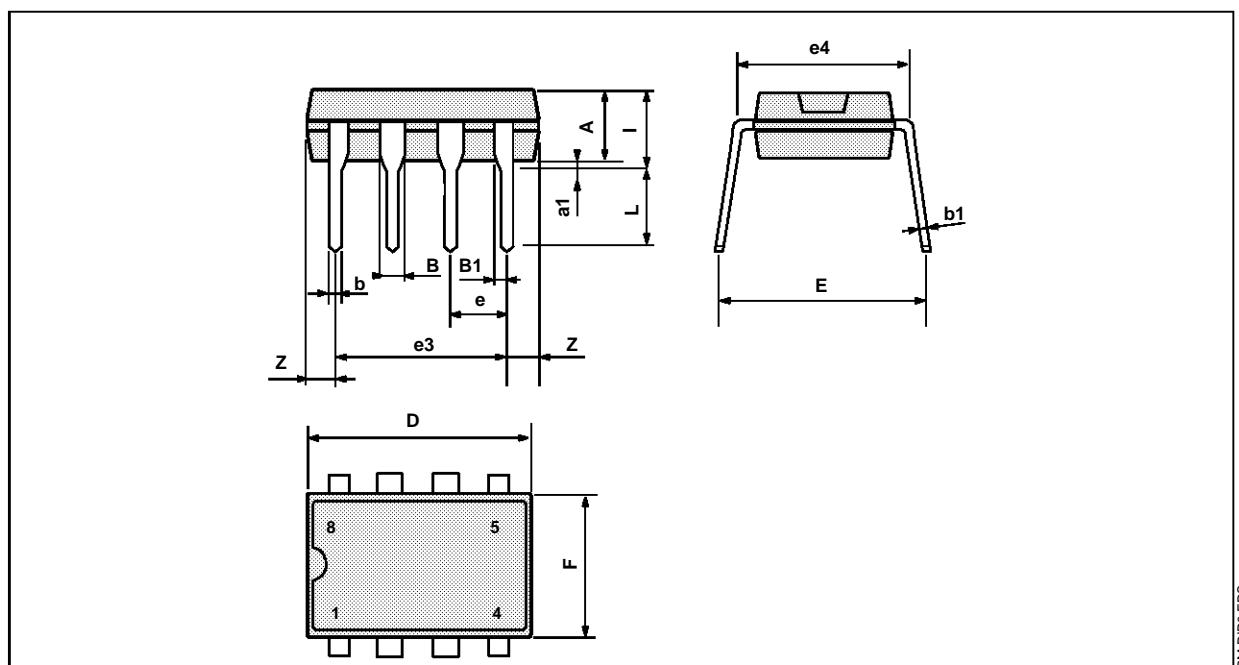
HIGH Q NOTCH FILTER



## TL071 - TL071A - TL071B

### PACKAGE MECHANICAL DATA

8 PINS - PLASTIC DIP

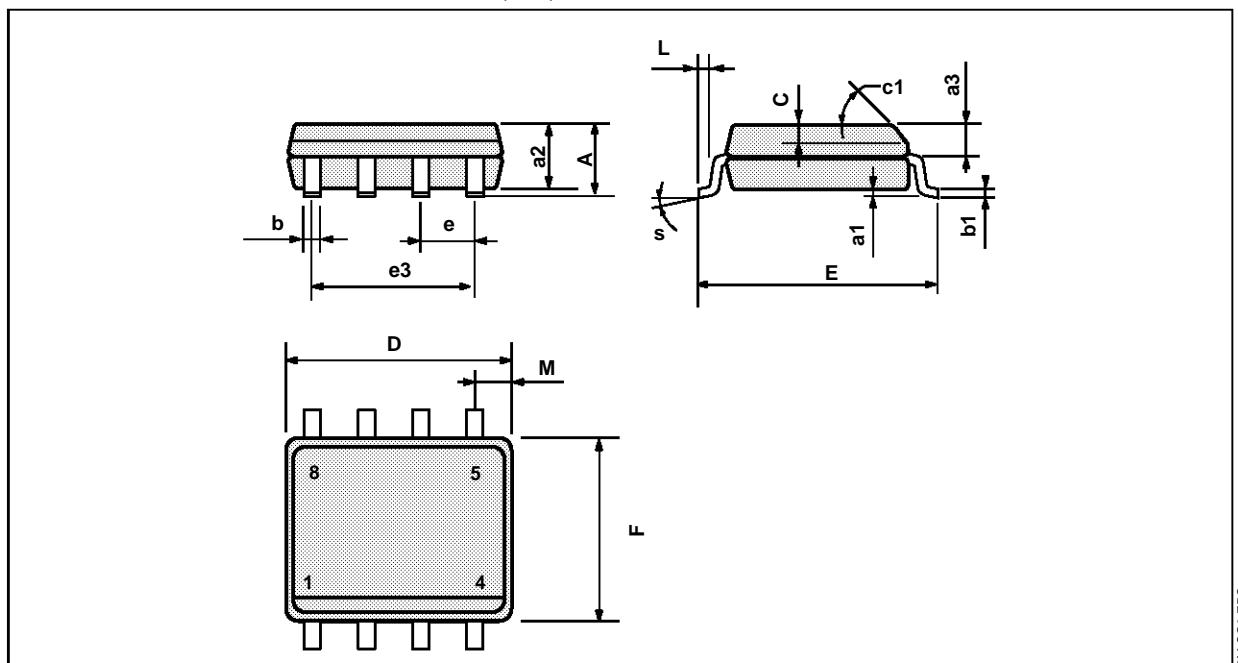


PM-DIP8.EPS

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A		3.32			0.131	
a1	0.51			0.020		
B	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D		10.92			0.430	
E	7.95		9.75	0.313		0.384
e		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			6.6			0.260
i			5.08			0.200
L	3.18		3.81	0.125		0.150
Z			1.52			0.060

DIP8.TBL

**PACKAGE MECHANICAL DATA**  
8 PINS - PLASTIC MICROPACKAGE (SO)



PM-S08.EPS

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.25	0.004		0.010
a2			1.65			0.065
a3	0.65		0.85	0.026		0.033
b	0.35		0.48	0.014		0.019
b1	0.19		0.25	0.007		0.010
C	0.25		0.5	0.010		0.020
c1	45° (typ.)					
D	4.8		5.0	0.189		0.197
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		3.81			0.150	
F	3.8		4.0	0.150		0.157
L	0.4		1.27	0.016		0.050
M			0.6			0.024
S	8° (max.)					

0  
7  
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